

MDD2601

Single N-channel Trench MOSFET 30V, 60.0A, 5.8m Ω

General Description

The MDD2601 uses advanced MagnaChip's MOSFET Technology, which provides high performance in on-state resistance, fast switching performance and excellent quality. MDD2601 is suitable device for DC to DC converter and general purpose applications.

Features

- $V_{DS} = 30V$
- $I_D = 60.0A$ @ $V_{GS} = 10V$
- $R_{DS(ON)} (MAX)$
 $< 5.8m\Omega$ @ $V_{GS} = 10V$
 $< 7.7m\Omega$ @ $V_{GS} = 4.5V$
- 100% UIL Tested
- 100% Rg Tested

